

[查询"LA6574D"供应商](#)**SANYO Semiconductors****DATA SHEET**

Monolithic Linear IC

LA6574D — Five-Channel Driver (four BTL channels plus one H bridge channel) for MD and CD Player**Overview**

The LA6574D is a motor driver IC for MD and CD players with four BTL channels and one H bridge channel. The LA6574D features a separate power supply for the H bridge block, an output adjustment pin, and a 3.3V regulator to support a wide range of applications.

Features and Features

- Four power amplifier channels plus one H bridge channel
- I_O max: 700mA (each channel)
- Built-in level shifting circuits for the BLT amplifiers
- Thermal protection circuit (Thermal shutdown circuit)
- Separate loading block power supply
- Built-in 3.3V regulator
- Provides a dedicated pin for adjusting the loading block output

SpecificationsMaximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V_{CC} max		14	V
Allowable power dissipation	P_d max	Independent IC	1.2	W
		Mounted on a specified board	2.0	W
Maximum output current	I_O max	Each channel for CH1 to CH5	0.7	A
Maximum input voltage	VINB		13	V
MUTE pin voltage	VMUTE		13	V
Operating temperature	T_{opr}		-30 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

* Mounted on a specified board: 76.1mm×114.3mm×1.6mm glass epoxy

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LA6574D

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		5.6 to 13	V

Electrical Characteristics at Ta = 25°C, V_{CC1} = V_{CC2} = 8V, V_{REF} = 1.65V

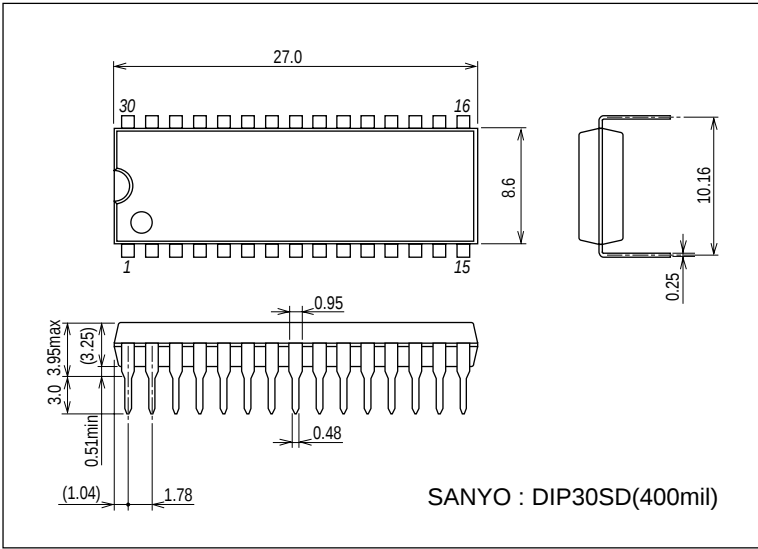
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[Overall Characteristics]						
No load current drain - I _{CC} on	I _{CC} -ON	All outputs on, FWD = REV = 0V *1		30	50	mA
VREF input voltage range	VREF-IN		1		V _{CC} -1.5	V
[BTL Amplifier Block]						
Output offset voltage	VOFF	BTL amplifiers, the voltage difference across each channel's output	-50		50	mV
Input voltage range	V _{IN}	Input resistance: 11kΩ	0		V _{CC}	V
Output voltage	V _O	The voltage between each of the V _O + /V _O - pairs when R _L is 8Ω. *2	4	5		V
Closed loop voltage gain	VG	Gain from input to output		4		Times
Slew rate	SR	With the amplifier operating independently, twice the value measured between outputs *3		0.5		V/μs
[H Bridge Block]						
Output voltage	V _O -LOAD	The voltage between each of the V _O + /V _O - pairs when R _L is 8Ω. *2		6		V
Low-level input voltage	V _{IN} -L				1	V
High-level input voltage	V _{IN} -H		2			V
Output control voltage	VCONT	VCONT = 3V *2		3.5		V
[Regulator Block]						
Output voltage	Vreg	I _L = 100mA	3.05	3.3	3.55	V
Load regulation	ΔVRL	I _L = 0 to 200mA	-50	0	10	mV
Line regulation	ΔVV _{CC}	V _{CC} = 6 to 12V, I _L = 100mA	-15	21	60	mV

Note *1: The total current drain for V_{CC1} and V_{CC2} with no load.
*2: Voltage difference across the load (8Ω). With the outputs in the saturated state.
*3: Design guarantee value

Package Dimensions

unit : mm (typ)

3196A



LA6574D

Pin Functions

Pin No.	Pin Name	Description
1	REV	5CH (VLO) Output change pin (REV), Logic input for loading block
2	FWD	5CH (VLO) Output change pin (FWD), Logic input for loading block
3	S-GND	Signal system GND
4	VCONT	Channel 5 (VLO) output voltage control
5	V _{IN4}	Input pin for channel 4
6	V _{IN4G}	Input pin for channel 4 (for gain control)
7	V _{CC-S}	Signal system power (V _{CC1} and V _{CC2} short-circuited)
8	VREF-IN	Reference voltage input pin
9	REG-OUT	Regulator pin (External PNP collector)
10	REG-IN	Regulator pin (External PNP base)
11	V _{IN3G}	Input pin for channel 3 (for gain control)
12	V _{IN3}	Input pin for channel 3
13	V _{IN2G}	Input pin for channel 2 (for gain control)
14	V _{IN2}	Input pin for channel 2
15	V _{IN1G}	Input pin for channel 1 (for gain control)
16	V _{IN1}	Input pin for channel 1
17	V _{CC1}	Power for channels 1 and 2 (BTL), (V _{CC-S} and V _{CC2} short-circuited)
18	(NC)	No connect
19	V _{O1} ⁻	Output pin (-) for channel 1
20	V _{O1} ⁺	Output pin (+) for channel 1
21	V _{O2} ⁻	Output pin (-) for channel 2
22	V _{O2} ⁺	Output pin (+) for channel 2
23	P-GND	Power GND
24	V _{O3} ⁻	Output pin (-) for channel 3
25	V _{O3} ⁺	Output pin (+) for channel 3
26	V _{O4} ⁻	Output pin (-) for channel 4
27	V _{O4} ⁺	Output pin (+) for channel 4
28	V _{O5} ⁺	Loading output (+)
29	V _{O5} ⁻	Loading output (-)
30	V _{CC2}	Power for channels 3, 4, and 5 (V _{CC1} and V _{CC-S} short-circuited)

*The P-GND functions as power system GND. Set this to the minimum potential together with S-GND.

*Short-circuit three pins of power system, V_{CC-S}, V_{CC1}, and V_{CC2}, externally before use.

Pin Description

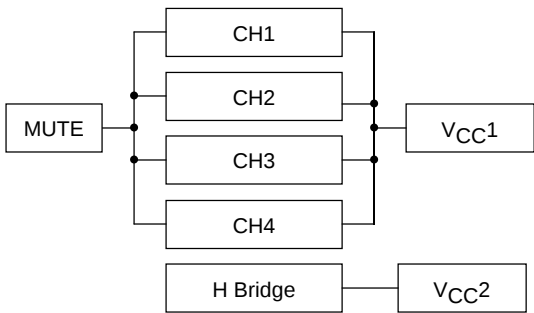
Pin No.	Symbol	Pin Name	Description	Equivalent Circuit
5 6 11 12 13 14 15 16	V_{IN4} V_{IN4G} V_{IN3G} V_{IN3} V_{IN2G} V_{IN2} V_{IN1G} V_{IN1}	Input	Input pin for each channel	
19 20 21 22 24 25 26 27	V_{O1-} V_{O1+} V_{O2-} V_{O2+} V_{O3-} V_{O3+} V_{O4-} V_{O4+}	Output	Each output	
28 29 4	V_{O5+} V_{O5-} VCONT	V_{O5}	H bridge output	
2 1	FWD REV	FWD REV	H bridge input	

H Bridge Block

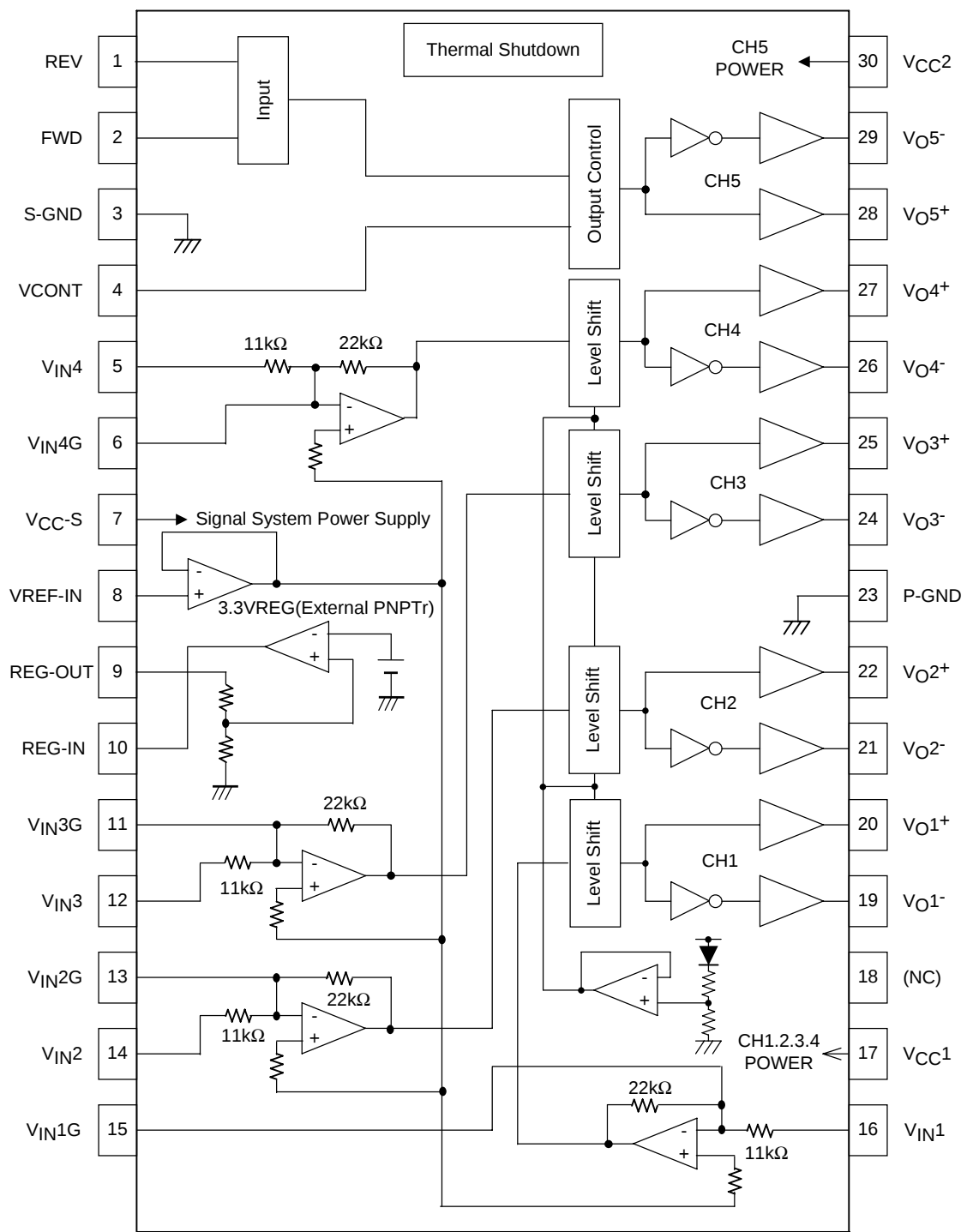
FWD	REV	V _{O5+}	V _{O5-}	Mode
L	L	OFF	OFF	Open *1
L	H	H	L	Forward
H	L	L	H	Reverse
H	H	L	L	Brake *2

- *1: Output: High impedance
*2: In case of braking, the SINK side transistor is turned ON (short brake). VLO+ and VLO- are approximately on the GND level.
*3: VCONT (output voltage setting pin) and VLO have the following relationship: $VLO = VCONT - 1V$ (typical)

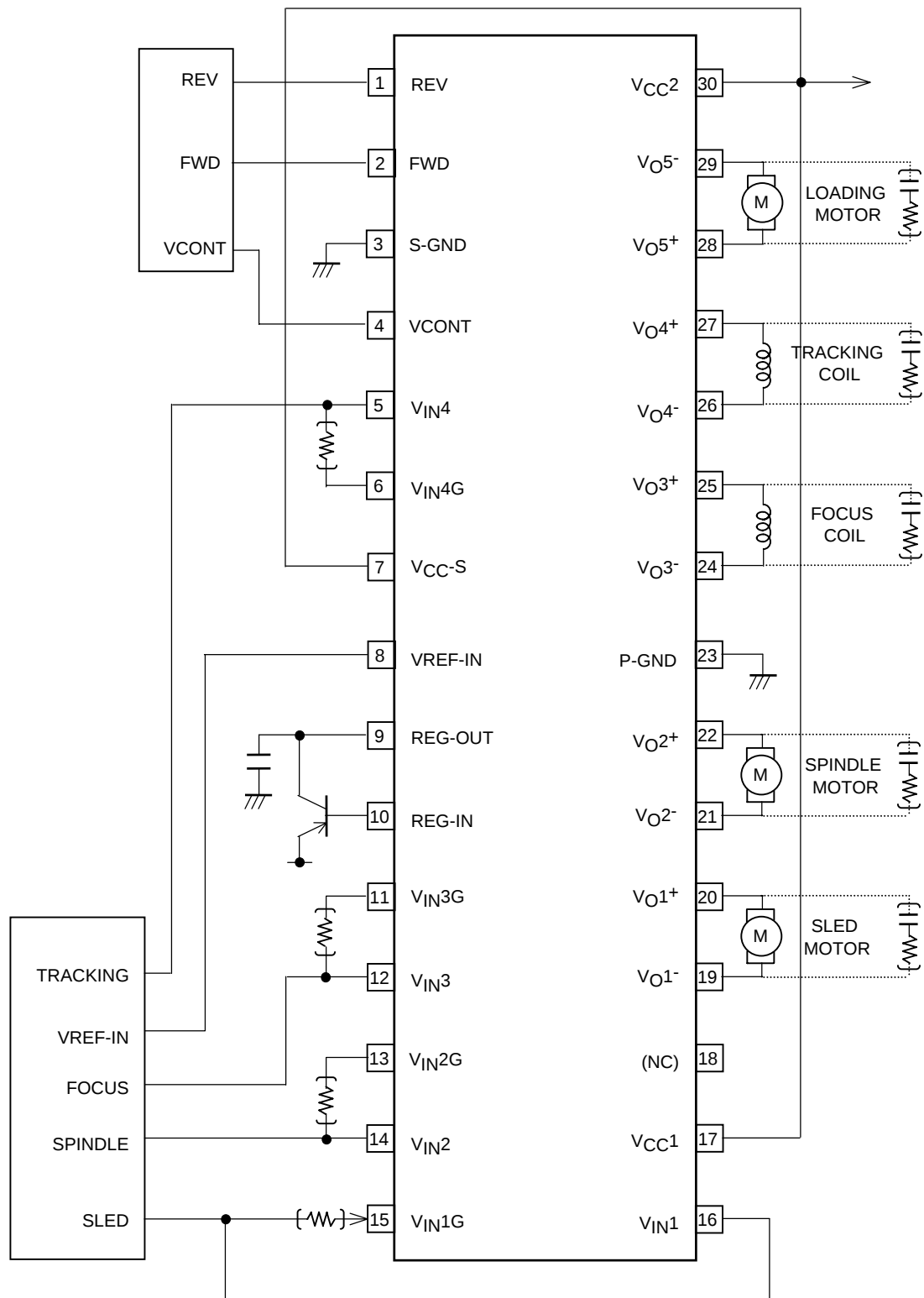
Relationship between the MUTE pin and the power supplies (VCC*)



Block Diagram



Sample Application Circuit



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